## NSN 5961-01-166-7500



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-166-7500 **Inclosure Material:** Metal **Overall Length:** 0.560 inches **Overall Height:** 0.725 inches **Overall Width:** 0.240 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 20.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 8.75 watts small-signal input power, common-collector preset **Transfer Ratio:** 20.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** 

Junction pattern arrangement: npn

**Thread Series Designator:** 

Unc

**Terminal Type And Quantity:** 

2 ribbon and 1 threaded stud

Shelf Life:

N/a

**Unit Of Measure:** 

Demilitarization:

No

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